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# FH105A

## RF Transistor 10V, 30mA, $f_T=8\text{GHz}$ , NPN Dual MCP6

ON Semiconductor®

<http://onsemi.com>

### Features

- Composite type with 2 transistors contained in the MCP package currently in use, improving the mounting efficiency greatly
- The FH105A is formed with two chips, being equivalent to the 2SC5245A, placed in one package
- Optimal for differential amplification due to excellent thermal equilibrium and pair capability

### Specifications

**Absolute Maximum Ratings** at  $T_a=25^\circ\text{C}$

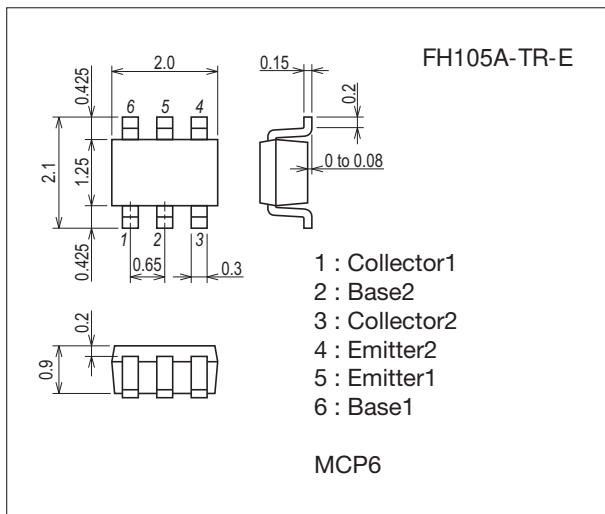
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		20	V
Collector-to-Emitter Voltage	$V_{CEO}$		10	V
Emitter-to-Base Voltage	$V_{EBO}$		1.5	V
Collector Current	$I_C$		30	mA
Collector Dissipation	$P_C$	When mounted on ceramic substrate (250mm <sup>2</sup> ×0.8mm) 1unit	150	mW
Total Power Dissipation	$P_T$	When mounted on ceramic substrate (250mm <sup>2</sup> ×0.8mm)	300	mW
Junction Temperature	$T_j$		150	°C
Storage Temperature	$T_{stg}$		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### Package Dimensions

unit : mm (typ)

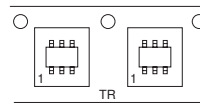
7026A-005



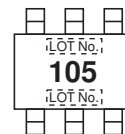
### Product & Package Information

- Package : MCP6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

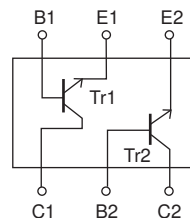
### Packing Type : TR



### Marking



### Electrical Connection



# FH105A

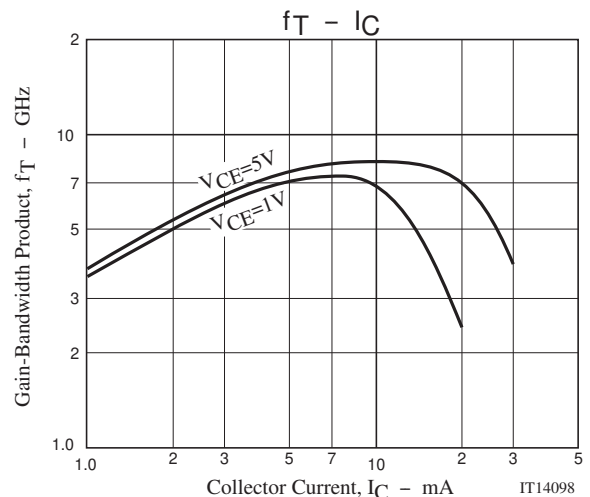
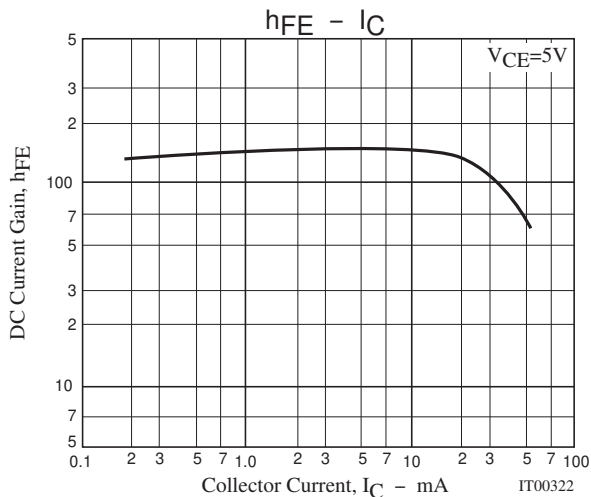
## Electrical Characteristics at Ta=25°C

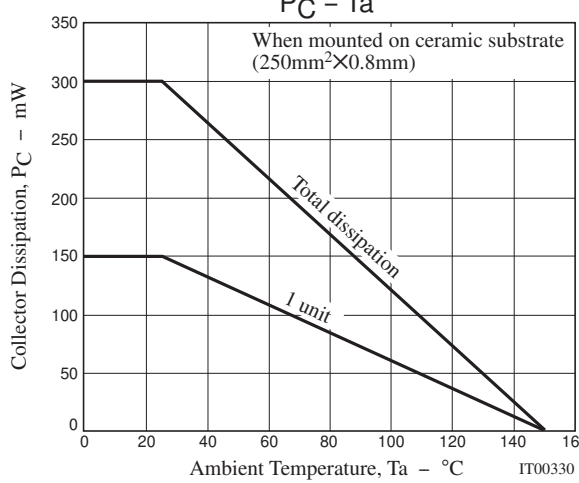
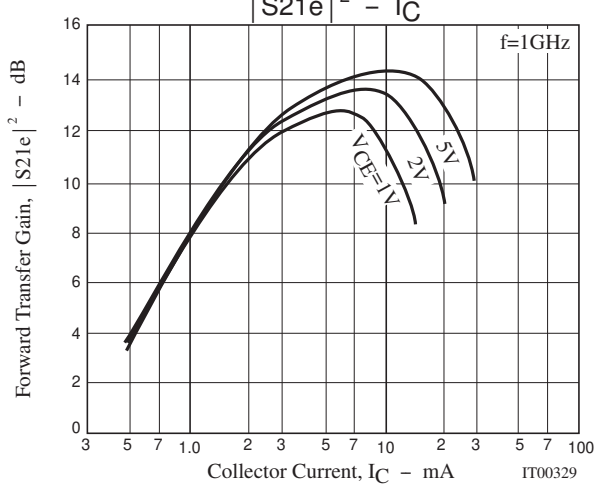
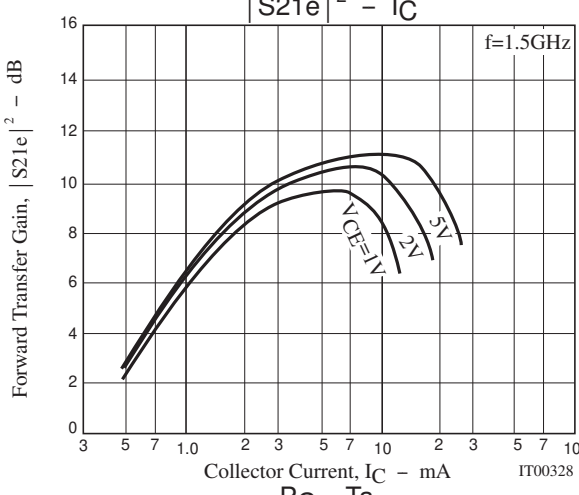
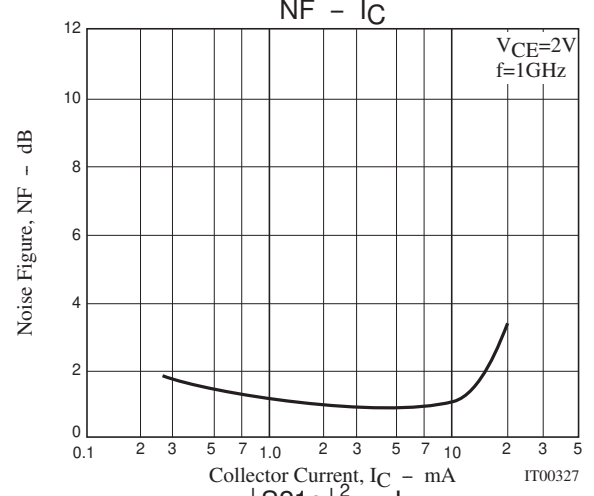
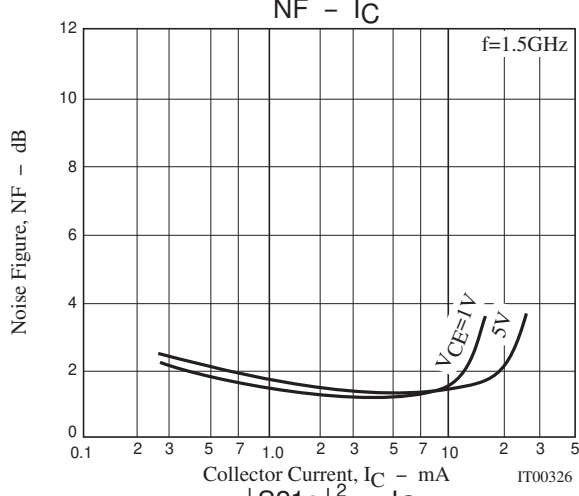
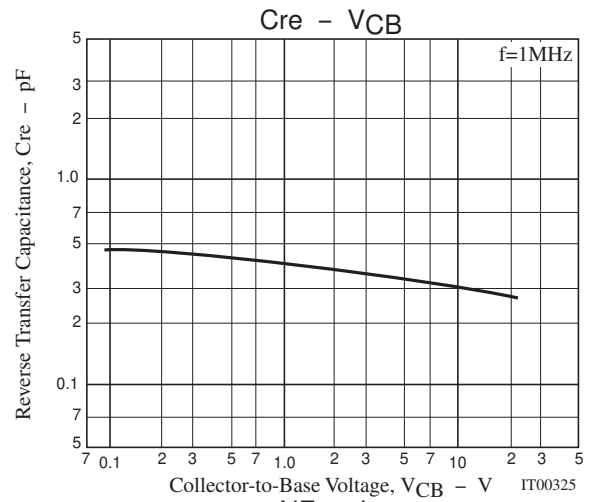
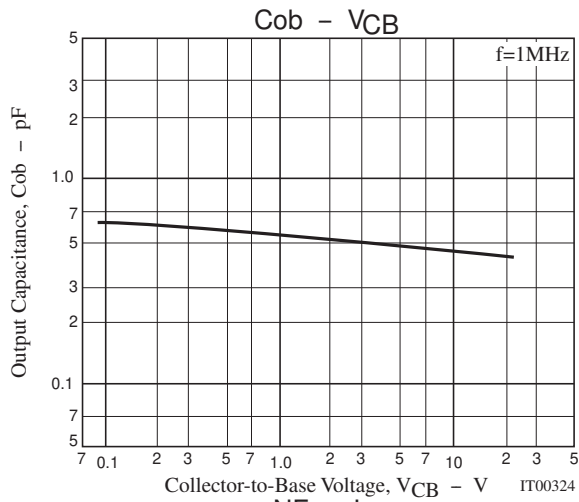
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =10V, I <sub>E</sub> =0A			1.0	μA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =1V, I <sub>C</sub> =0A			10	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	90		200	
DC Current Gain Ratio	h <sub>FE</sub> (small/large)	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	0.7	0.95		
Base-to-Emitter Voltage Difference	V <sub>BE</sub> (large-small)	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA		1.0		mV
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	5	8		GHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		0.45	0.7	pF
Forward Transfer Gain	S <sub>21e</sub>   <sup>2</sup>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=1.5GHz	8	10		dB
Noise Figure	NF	V <sub>CE</sub> =5V, I <sub>C</sub> =5mA, f=1.5GHz		1.4	3.0	dB

Note) The specifications shown above are for each individual transistor except the h<sub>FE</sub>(small/large) and V<sub>BE</sub> (large-small) for which pair capability is also shown.

## Ordering Information

Device	Package	Shipping	memo
FH105A-TR-E	MCP6	3,000pcs./reel	Pb Free



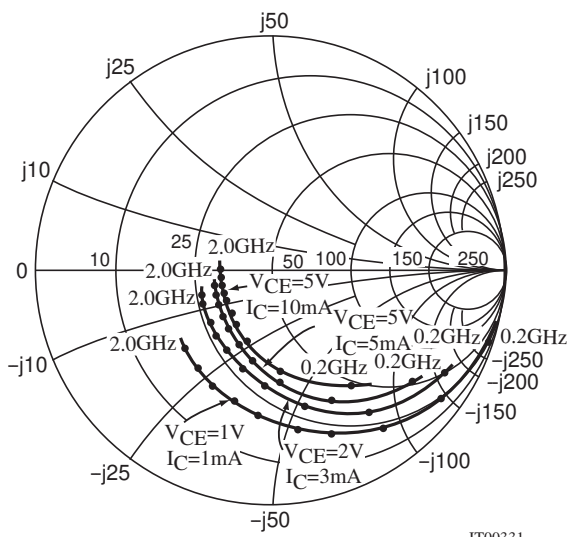


# FH105A

## S Parameter

S11e

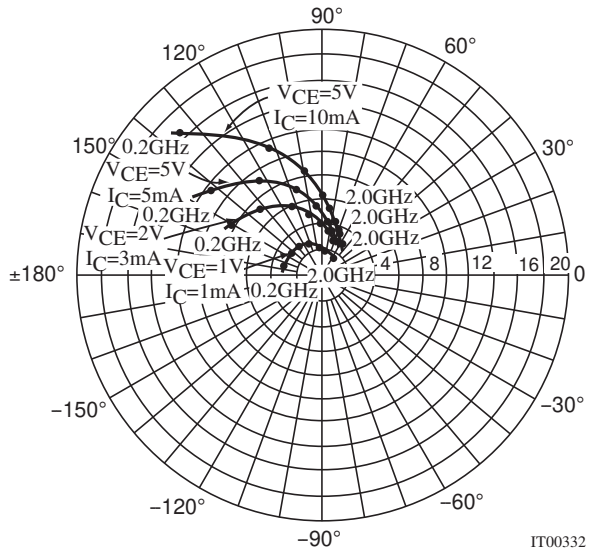
f=200MHz to 2000MHz(200MHz Step)



IT00331

S21e

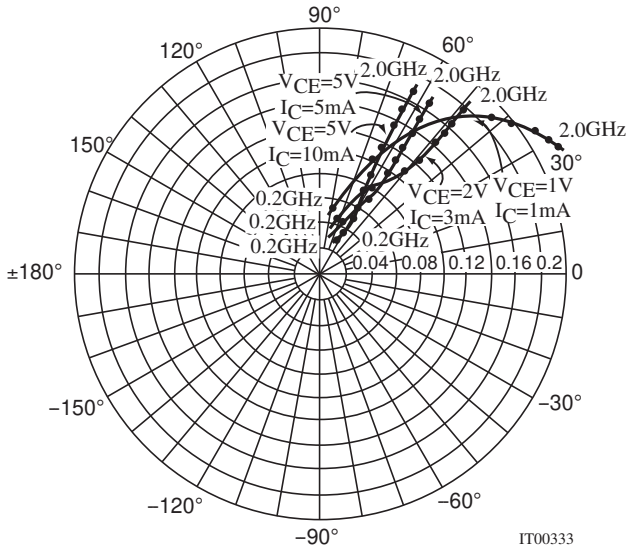
f=200MHz to 2000MHz(200MHz Step)



IT00332

S12e

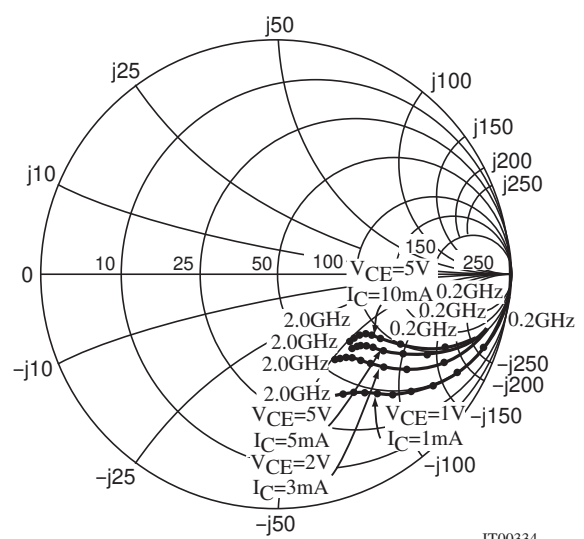
f=200MHz to 2000MHz(200MHz Step)



IT00333

S22e

f=200MHz to 2000MHz(200MHz Step)



IT00334

# FH105A

## S Parameters (Common emitter)

$V_{CE}=5V, I_C=5mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
200	0.763	-37.5	11.926	146.9	0.036	70.7	0.892	-19.1
400	0.590	-65.4	9.202	124.3	0.058	60.9	0.740	-29.1
600	0.456	-85.5	7.173	109.4	0.073	57.4	0.631	-33.7
800	0.374	-102.0	5.743	98.7	0.086	56.7	0.566	-35.8
1000	0.323	-115.0	4.785	90.5	0.098	56.7	0.528	-37.2
1200	0.288	-127.5	4.105	83.6	0.110	57.2	0.505	-38.4
1400	0.264	-137.7	3.599	77.5	0.123	57.7	0.488	-39.6
1600	0.248	-147.4	3.213	71.3	0.136	57.6	0.476	-41.2
1800	0.239	-156.9	2.905	66.4	0.150	57.6	0.466	-43.3
2000	0.235	-165.7	2.651	61.3	0.165	57.2	0.462	-45.4

$V_{CE}=5V, I_C=10mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
200	0.605	-52.6	16.354	136.2	0.031	67.5	0.804	-23.9
400	0.417	-84.6	11.011	113.3	0.048	62.4	0.622	-30.5
600	0.319	-106.3	8.026	100.5	0.062	62.2	0.533	-32.0
800	0.266	-124.6	6.250	91.3	0.076	63.4	0.491	-32.4
1000	0.238	-136.5	5.115	84.7	0.090	64.3	0.469	-33.2
1200	0.225	-148.9	4.336	78.8	0.104	64.4	0.458	-34.6
1400	0.215	-158.3	3.813	73.4	0.119	64.5	0.449	-35.8
1600	0.213	-167.3	3.365	68.1	0.135	63.8	0.443	-37.7
1800	0.212	-175.6	3.030	63.5	0.150	63.1	0.436	-39.6
2000	0.216	-177.5	2.754	58.9	0.166	62.5	0.438	-41.9

$V_{CE}=2V, I_C=3mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
200	0.842	-30.7	8.491	153.0	0.044	72.5	0.931	-17.1
400	0.704	-56.3	7.161	131.9	0.075	60.9	0.808	-28.8
600	0.579	-76.1	5.879	116.3	0.095	54.1	0.696	-36.2
800	0.480	-93.1	4.882	104.2	0.109	51.0	0.615	-40.6
1000	0.417	-106.3	4.154	95.0	0.121	49.3	0.564	-43.5
1200	0.376	-119.6	3.597	87.1	0.132	48.7	0.526	-45.8
1400	0.343	-130.2	3.212	80.2	0.143	48.6	0.496	-47.5
1600	0.319	-140.5	2.875	73.4	0.154	48.7	0.475	-49.6
1800	0.303	-150.0	2.604	67.7	0.166	48.6	0.461	-51.6
2000	0.298	-160.0	2.383	62.1	0.179	48.9	0.451	-52.9

$V_{CE}=1V, I_C=1mA, Z_O=50\Omega$

Freq(MHz)	S11	$\angle S11$	S21	$\angle S21$	S12	$\angle S12$	S22	$\angle S22$
200	0.945	-18.9	3.296	162.5	0.054	77.2	0.980	-11.0
400	0.884	-37.3	3.206	145.9	0.102	65.9	0.934	-20.5
600	0.810	-53.6	2.942	131.2	0.139	56.3	0.870	-29.0
800	0.728	-69.4	2.711	117.8	0.166	48.6	0.811	-35.5
1000	0.667	-82.5	2.449	107.0	0.187	42.5	0.763	-40.9
1200	0.605	-95.8	2.252	96.9	0.199	37.3	0.715	-45.7
1400	0.561	-106.1	2.061	88.1	0.207	33.5	0.673	-49.4
1600	0.518	-117.2	1.909	79.5	0.212	30.6	0.638	-53.4
1800	0.492	-127.5	1.766	72.2	0.215	28.6	0.611	-56.5
2000	0.465	-137.9	1.658	65.2	0.217	27.6	0.592	-59.9

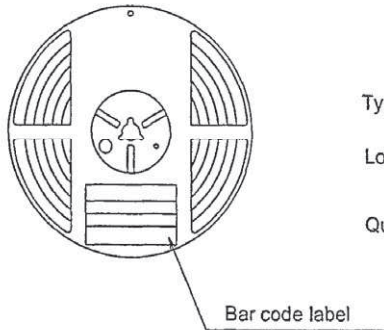
Embossed Taping Specification

FH105A-TR-E

Storage package Outline name	Carrier tape Type number	Maximum Number of devices contained (pcs.)			Packing format	
		Reel	Inner box	Outer box	Inner box BOX (C-1)	Outer box BOX (A-7)
MCP 6	MCP 6	3,000	15,000	90,000	5 reels contained Dimensions:mm(external) 1 8 3 × 7 2 × 1 8 5	6 inner boxes contained Dimensions:mm(external) 4 4 0 × 1 9 5 × 2 1 0

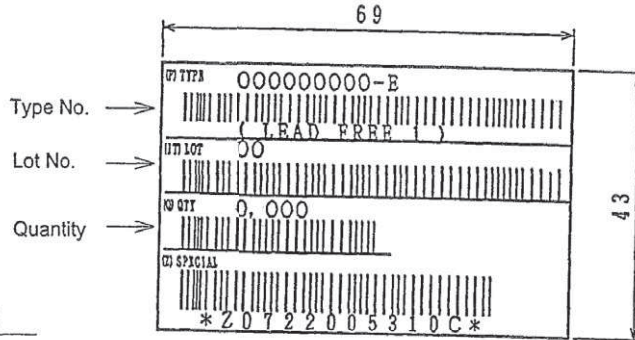
1. Packing format

Packing method



Bar code label

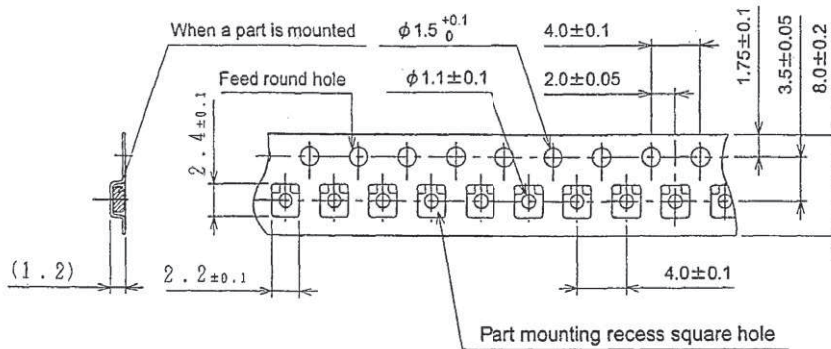
(Unit : mm)



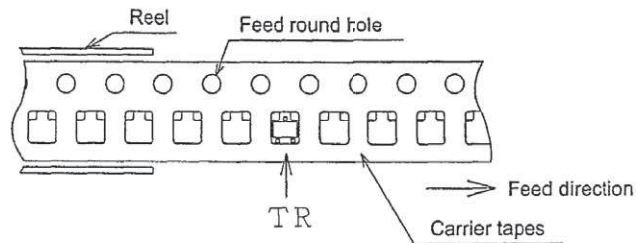
\* LEAD FREE 1 :  
Lead-free external terminal surface treatment product.

2. Taping structure

2-1. Carrier tape size (Unit : mm)



2-2. Parts placement direction

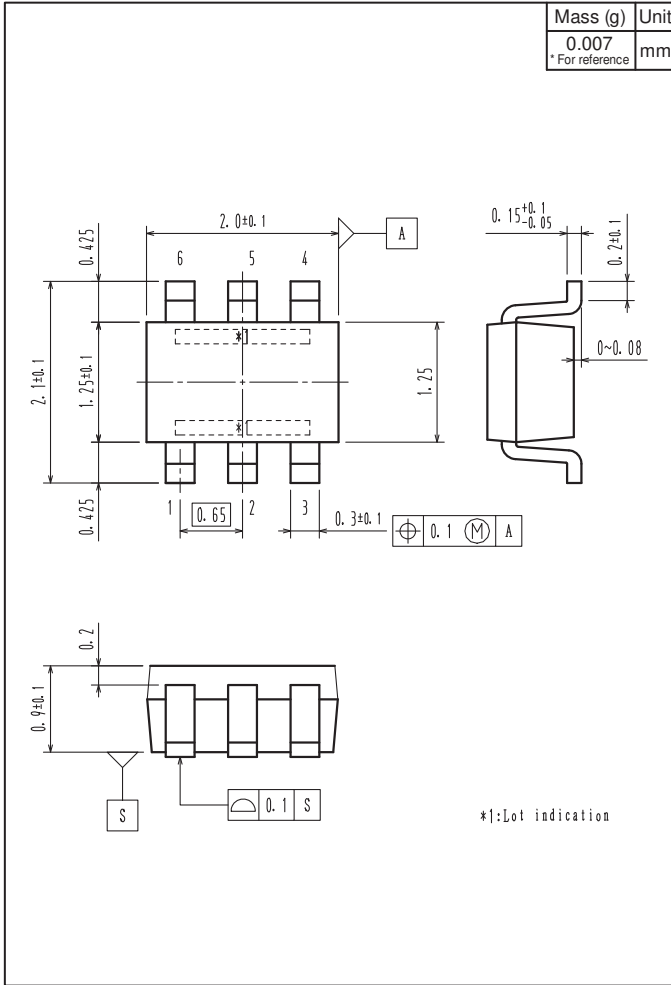


Those with 1 electrode pin on the feed hole side . . . TR

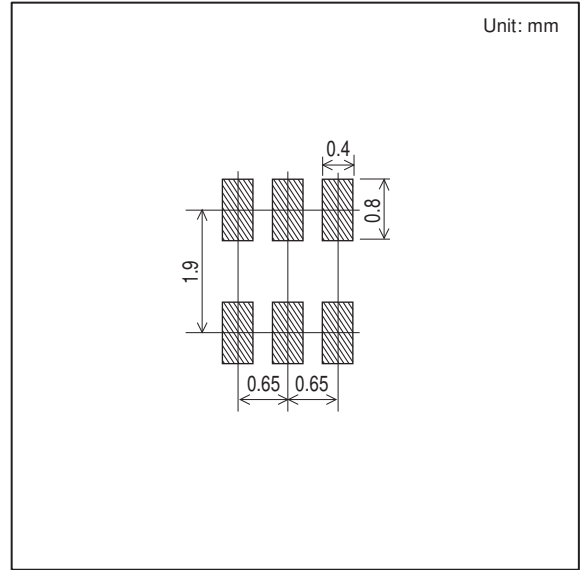
# FH105A

## Outline Drawing

FH105A-TR-E



## Land Pattern Example





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